

## High voltage fast switching NPN power transistor

Datasheet — production data

#### **Features**

- High voltage capability
- Fast switching speed

### **Applications**

- Lighting
- Switch mode power supply

#### **Description**

This device is a high voltage fast-switching NPN power transistor. It is manufactured using high voltage multi epitaxial planar technology for high switching speeds and medium voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining a wide RBSOA. The device is designed for use in lighting applications and low cost switch-mode power supplies.

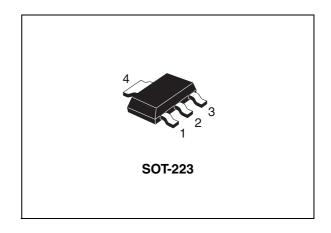


Figure 1. Internal schematic diagram

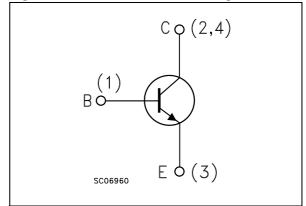


Table 1. Device summary

Order codes	Marking	Package	Packaging	
STN2580	N2580	SOT-223	Tape and reel	

Contents STN2580

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STN2580 Electrical ratings

# 1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V <sub>CES</sub>	Collector-emitter voltage (V <sub>BE</sub> = 0)	800	V
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	400	V
V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0)	9	V
I <sub>C</sub>	I <sub>C</sub> Collector current		Α
I <sub>CM</sub>	I <sub>CM</sub> Collector peak current (t <sub>P</sub> < 5 ms)		Α
I <sub>B</sub>	I <sub>B</sub> Base current		Α
P <sub>TOT</sub>	P <sub>TOT</sub> Total dissipation at T <sub>amb</sub> = 25 °C		W
T <sub>STG</sub>	Storage temperature	-65 to 150	°C
T <sub>J</sub>	Max. operating junction temperature		°C

Table 3. Thermal data

	Symbol	Parameter	Value	Unit
ĺ	$R_{thJA}$	Thermal resistance junction-ambient max <sup>(1)</sup>	78	°C/W

<sup>1.</sup> When mounted on PCB area of 1cm<sup>2</sup>

Electrical characteristics STN2580

### 2 Electrical characteristics

 $T_{case}$  = 25 °C unless otherwise specified.

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current (I <sub>E</sub> = 0)	V <sub>CB</sub> = 800 V			10	μΑ
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 8 V			100	μΑ
V <sub>(BR)CEO</sub> (1)	Collector-emitter breakdown voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 10 mA				V
V <sub>(BR)EBO</sub>	Emitter-base breakdown voltage $(I_C = 0)$	I <sub>E</sub> = 100 μA	9			V
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	$I_C = 250 \text{ mA}$ $V_{CE} = 5 \text{ V}$	60	100		
V <sub>CE(sat)</sub> (1)	Collector-emitter saturation voltage	I <sub>C</sub> = 1 A I <sub>B</sub> = 0.2 A			1	V
V <sub>BE(sat)</sub> (1)	Base-emitter saturation voltage	I <sub>C</sub> = 1 A I <sub>B</sub> = 0.2 A			1.1	V
	Resistive load					
t <sub>r</sub>	Rise time	V <sub>CC</sub> =200 V, I <sub>C</sub> =0.3 A		140		ns
t <sub>s</sub>	Storage time	I <sub>B1</sub> =20 mA, I <sub>B2</sub> =-50 mA		4		μs
t <sub>f</sub>	Fall time	T <sub>p</sub> =30 μs		90		ns

<sup>1.</sup> Pulse test: pulse duration  $\leq$ 300  $\mu$ s, duty cycle  $\leq$ 2%

### 2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Pulse operation\*

100 ms

1 ms

100 µs

Voe [V]

Figure 3. Derating curve

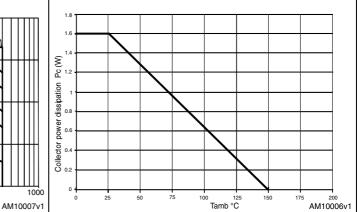


Figure 4. Output curves up to V<sub>CE</sub>=2 V

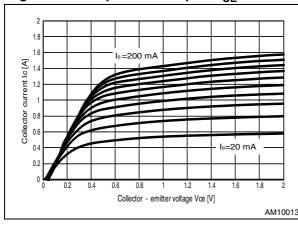


Figure 5. Output curves up to  $V_{CE}=10 \text{ V}$ 

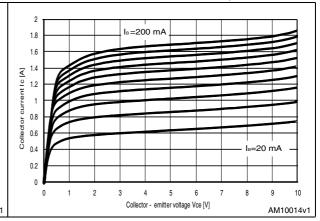


Figure 6. DC current gain  $(V_{CE} = 1 V)$ 

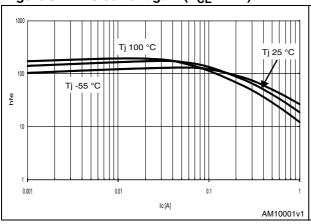
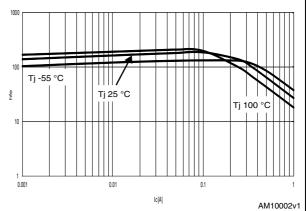


Figure 7. DC current gain  $(V_{CE} = 5 V)$ 



Electrical characteristics STN2580

Figure 8. Collector-emitter saturation voltage Figure 9. Base-emitter saturation voltage

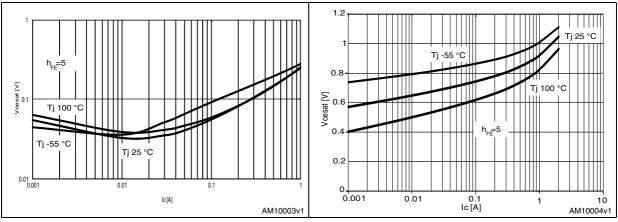


Figure 10. Base-emitter on voltage

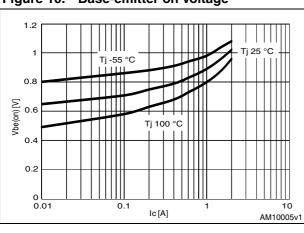


Figure 11. Capacitance variation

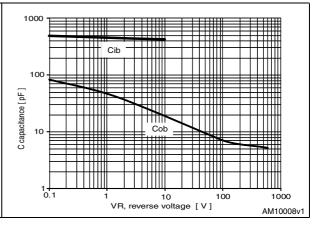


Figure 12. Resistive switching time

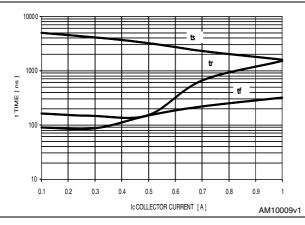


Figure 13. V<sub>be(sat)</sub> vs. I<sub>C</sub>

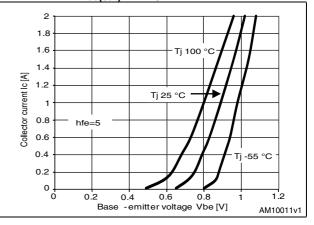
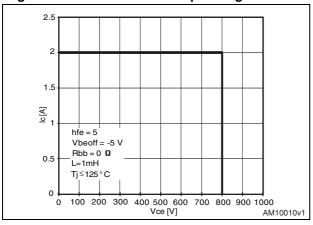


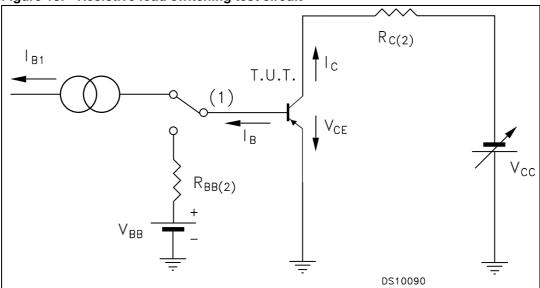
Figure 14. Reverse biased operating area



Test circuit STN2580

### 3 Test circuit

Figure 15. Resistive load switching test circuit



- 1. Fast electronic switching
- 2. Non-inductive resistor

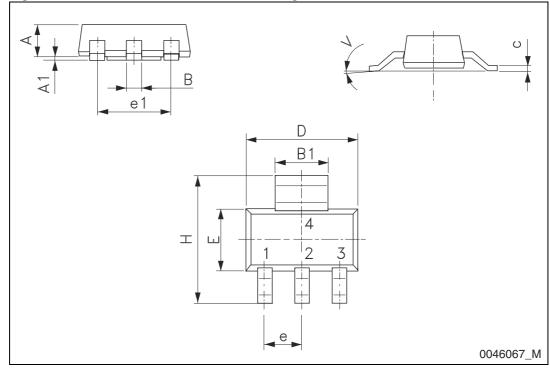
## 4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

Table 5. SOT-223 mechanical data

Dim.	mm				
Dini.	Min.	Тур.	Max.		
Α			1.80		
A1	0.02		0.1		
В	0.60	0.70	0.85		
B1	2.90	3.00	3.15		
С	0.24	0.26	0.35		
D	6.30	6.50	6.70		
е		2.30			
e1		4.60			
E	3.30	3.50	3.70		
Н	6.70	7.00	7.30		
V			10°		

Figure 16. SOT-223 mechanical data drawing



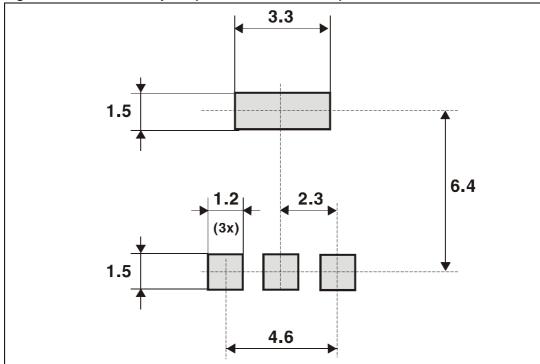


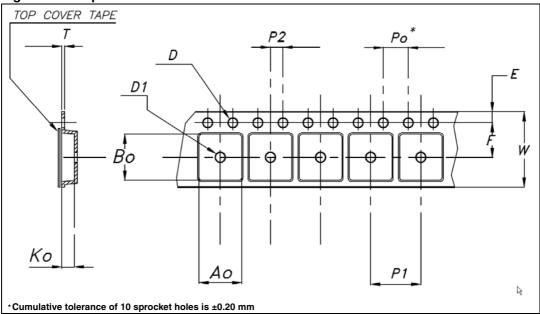
Figure 17. SOT-223 footprint (dimensions are in mm)

# 5 Packaging mechanical data

Table 6. SOT-223 tape and reel mechanical data

Таре				Reel		
Dim.	mm Dim			Dim	mm	
DIM.	Min.	Тур.	Max.	Dim.	Min.	Max.
A0	6.75	6.85	6.95	А		180
В0	7.30	7.40	7.50	N	60	
K0	1.80	1.90	2.00	W1		12.4
F	5.40	5.50	5.60	W2		18.4
E	1.65	1.75	1.85	W3	11.9	15.4
W	11.7	12	12.3			
P2	1.90	2	2.10	Base qua	antity pcs	1000
P0	3.90	4	4.10	Bulk qua	antity pcs	1000
P1	7.90	8	8.10			
Т	0.25	0.30	0.35			
Dφ	1.50	1.55	1.60			
D1¢	1.50	1.60	1.70			

Figure 18. Tape for SOT-223



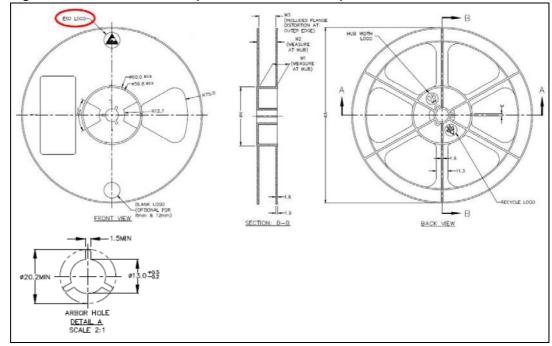


Figure 19. Reel for SOT-223 (dimensions are in mm)

Revision history STN2580

# 6 Revision history

Table 7. Document revision history

Date	Revision	Changes	
30-Oct-2012	1	Initial release.	
10-Jan-2013	2	Added new section: Packaging mechanical data	

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